

785 nm Grating Stabilized, Single-Frequency Laser Diode





Description

The FPV785P 785 nm, Single-Frequency, Wavelength-Stabilized Laser Diode is based on quantum well epitaxial layer growth and a highly reliable ridge waveguide structure with external volume-holographic-grating (VHG) feedback. This single-frequency laser diode is housed in a butterfly package with an internal optical isolator, monitor diode, TEC and a thermistor that allows the laser to be temperature controlled. This laser diode produces a wavelength-stabilized spectrum with a single-frequency narrow linewidth over the operating power range of approximately 30 to 50 mW. The output is coupled to 1.0 m of FC/APC-terminated PM780-HP fiber.

Specifications

Absolute Maximum Ratings ^a				
LD Reverse Voltage (Max)	2 V			
PD Reverse Voltage (Max)	20 V			
Absolute Max Current	410 mA			
Absolute Max Power	100 mW			
Operating Case Temperature	0 to 70 °C			
Storage Temperature	-10 to 70 °C			
Pin Code	14 Pin, Type 1			

a. Do not exceed the maximum optical power or maximum drive current, whichever occurs first.

Characteristics (CW; T _{CHIP} = T _{CS} , T _{CASE} = 0 - 70 °C)						
	Symbol	Min	Typical	Max		
Center Wavelength	λc	784 nm	785 nm	786 nm		
Single Frequency Output Power ^a (CW @ I _{CW} and T _{CS})	P _{CW-SF}	40 mW	50 mW	-		
Single Frequency Power Range	ΔP_{SF}	20 mW ^b	-	-		
Operating Current (CW)	I _{CW}	-	-	410 mA		
Center Temperature for $\Delta T_{stabilized}$	T _{CS}	15 °C	-	35 °C		
Wavelength-Stabilized Temperature Range	ΔT _{stabilized}	5 °C	-	-		
Threshold Current	I _{TH}	-	80 mA	150 mA		
Side Mode Suppression Ratio (SMSR)	SMSR	25 dB	40 dB	-		
Internal Isolator Isolation	ISO	35 dB	-	-		
Forward Voltage	V_{F}	-	2.1 V	2.8 V		
Slope Efficiency at 25 °C	ΔΡ/ΔΙ	-	0.25 W/A	-		
Laser Linewidth	Δv	-	15 MHz	-		
Monitor Photodiode Current	Iphoto	-	0.15 mA	-		
Polarization Extinction Ratio	PER	15 dB				
TEC Operation (Typical/Max @ T _{CASE} = 25 °C / 70 °C)						
-TEC Current	I _{TEC}	-	0.13 A	1.4 A		
-TEC Voltage	V _{TEC}	-	0.40 V	6.0 V		
-Thermistor Resistance	R _{TH}	-	10 kΩ	-		

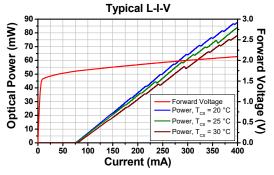
a. This value is the upper limit of the range where the diode can produce a single-frequency output and varies from laser to laser. The performance of each individual laser can be found on the unit-specific data sheet.

b. Multimode operation may occur below a minimum power threshold. This minimum power threshold can be found by subtracting the single frequency power range, ΔP_{SF} , from the maximum power, P_{CW-SF} . The maximum power will vary by item; see the item-specific data sheet for these values. This is valid over the temperature range $T_{CS} \pm \Delta T_{Stabilized}/2$.

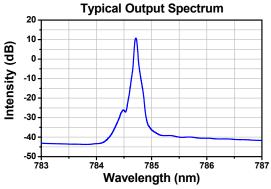


Typical Performance Plots

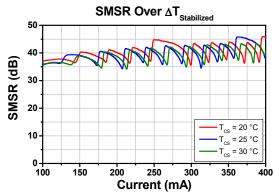
The plots below are typical; performance will vary between individual lasers. Each laser includes a serial-number-specific datasheet detailing performance.



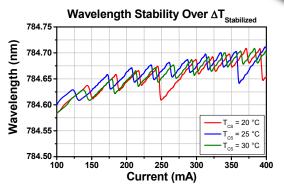
The typical output power vs. current is shown for three temperatures within the wavelength stabilized temperature range $(T_{CS} \pm \Delta T_{stabilized}/2)$ of a FPV785P laser diode.



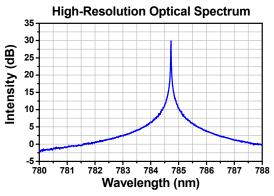
The typical optical spectrum is shown above. The data was obtained with a 400 mA drive current and the device held at 25 °C.



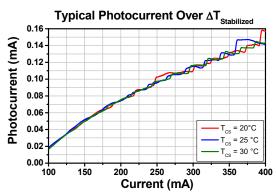
The typical side mode suppression ratio (SMSR) is shown for three temperatures within the wavelength stabilized temperature range ($T_{CS} \pm \Delta T_{stabilized}/2$).



When used within the wavelength stabilized temperature range ($T_{CS} \pm \Delta T_{stabilized}/2_d$), the FPV785P laser shows excellent wavelength stability over a range of drive currents.



This high-resolution optical spectrum was obtained using one of Thorlabs' Optical Spectrum Analyzers (OSA201C), which provides 8 pm resolution at 785 nm.



The typical monitor photodiode current over laser diode current is shown above.



Drawing

